Diode Semiconductor Device - Page 1 of 1

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## Inclosure Material:

Glass
Overall Length:
Between 0.120 inches and 0.200 inches
Terminal Length:
1.000 inches

Overall Diameter:
Between 0.055 inches and 0.090 inches

## Mounting Method:

Terminal

## Features Provided:

Hermetically sealed case

## Semiconductor Material:

Silicon

## Voltage Rating In Volts Per Characteristic:

8.2 regulator voltage

Voltage Tolerance In Percent:
-2.0 to 2.0

## Current Rating Per Characteristic:

20.00 milliamperes all primaries horsepower metric and 50.00 milliamperes repetitive peak forward current

## Power Rating Per Characteristic:

500.0 milliwatts small-signal input power, common-collector preset

## Maximum Operating Tempurature Per Measurement Point:

175.0 degrees celsius ambient air

## Test Data Document:

81349-mil-prf-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

## Terminal Type And Quantity:

2 uninsulated wire lead
Shelf Life:
N/a
Unit Of Measure:

## Demilitarization:

No
Fiig:
A110a0
Mil-std (military Standard):
Mil-prf-19500 spec.

